AI-Mn-Si (Aluminum-Manganese-Silicon)

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The pre-1990 experimental results of this ternary system were evaluated by [1993Pri]. The evaluated data were presented as liquidus and solidus projections near the Al corner, a full isothermal section at 950 °C from [1982Gas], partial sections near the Al corner at 720, 600, and 460 °C and two vertical sections at 4 mass % Si and 6 mass % Mn respectively. A comprehensive experimental and thermodynamic study of this ternary system was reported recently by [2002Kre] and [2004Du].

Binary Systems

The Al-Mn phase diagram [Massalski2, 1996Liu] has the following intermediate phases: ϵ (close packed hexagonal,

55–72 at. % Mn), γ (body centered cubic, ~ 34.5–52 at. % Mn), γ_1 (~ 30–38.7 at. % Mn, structure not known), γ_2 $(D8_{10}, Cr_5Al_8$ -type rhombohedral, ~ 31.4–50 at. % Mn,) Mn_4Al_{11} (triclinic), μ (hexagonal, 19–20.8 at. % Mn), λ (hexagonal, 16.8–19 at. % Mn), and MnAl₆ ($D2_h$ -type orthorhombic). The Al-Si phase diagram is a simple eutectic system with the eutectic at 577 °C and 12.2 at. % Si. The Mn-Si phase diagram [1991Oka] depicts the following intermediate phases: Mn₆Si (rhombohedral, denoted R), Mn_9Si_2 (orthorhombic, denoted v), βMn_3Si (D0₃-type cubic), Mn₅Si₂ (tetragonal), Mn₅Si₃ (D8₈-type hexagonal), MnSi (B20, FeSi-type cubic), and Mn₁₁Si₁₉ (tetragonal, denoted Mn15Si26 by [2002Kre]).Krendelsberger et al [2002Kre] reported new lattice parameter measurements for the above intermediate phases. [2004Du] presented computed phase diagrams of the above binary systems.

Table 1 Al-Mn-Si crystal structure and lattice parameter data [2002Kre]

Phase	Composition, atomic %	Pearson symbol	Space group	Prototype	Lattice parameter, nm
$\overline{Al_2Mn_2Si_3(\tau_1)}$	28.5 Al	hP21	PĒ		a = 0.96121
	28 Mn				c = 0.35640
	43.5 Si				
$Al_3Mn_3Si_4(\tau_2)$	29 Al	hP9	P6222	CrSi ₂	a = 0.44874
	34 Mn				c = 0.64419
	37 Si				
AlMnSi (τ ₃)	34 Al	oF24	Fddd	TiSi ₂	a = 0.78695
	34 Mn				b = 0.45375
	32 Si				c = 0.85175
Al ₃ MnSi ₂ (τ_4)	52 Al	<i>tP</i> 48	P4/n		a = 1.2312
	15.5 Mn				c = 0.4908
	32.5 Si				
$Al_3Mn_4Si_2$ (τ_5)	33.3-40 Al				a = 2.295
	44.4-40 Mn				b = 3.159
	22.3-20 Si				c = 1.226
$Al_{2-x}Mn_{2+x}Si\ (\tau_6)$	40-30 Al				
	40-50 Mn				
	20 Si				
$AL_5Mn_4Si_{-1}~(\tau_7)$	50-52 Al				
	39-37 Mn				
	11 Si				
β AlMnSi (τ_8) (Mn ₃ (Al,Si) ₁₀)	70-61 Al	hP26	$P6_3/mmc$	Mn_3Al_{10}	a = 0.74491
	25-23 Mn				c = 0.77330
	5-16 Si				
αAlMnSi (τ ₉) (Al ₉ Mn ₂ Si)	71 Al	cP138	$Pm\bar{3}$		a = 1.26576
	17.1 Mn				
	11.9 Si				
$Al_2MnSi_3(\tau_{10})$	35 Al	<i>tI</i> 24	I4/mcm	Ga ₅ Pd	a = 0.60607
	17 Mn				c = 0.94422
	48 Si				



Fig. 1 Al-Mn-Si liquiudus projection [2002Kre]



Fig. 2 Al-Mn-Si isothermal section at 700 °C [2002Kre]

Ternary phases

Krendelsberger et al [2002Kre] confirmed ten ternary phases found in earlier work and determined their structural characteristics as listed in Table 1. α AlMnSi (τ_9) and β AlMnSi (τ_8) were the first ternary phases to be identified in this system. τ_6 and τ_8 have significant ranges of homogeneity. Al₂MnSi₃ (τ_{10}) is stable only between 846 °C and 743 °C. The presence of Al₅Mn₄Si₁ (τ_7) was detected only by energy dispersive x-ray analysis; neither its crystal structure nor the x-ray powder patterns were elucidated [2002Kre].



Fig. 3 Al-Mn-Si isothermal section at 550 °C [2002Kre]



Fig. 4 Al-Mn-Si computed vertical section at 4 mass % Mn [2004Du]

Liquidus Projection

With starting metals of 99.999 % Al, 99.95 % Mn and 99.99 % Si, [2002Kre] prepared about 100 ternary alloys. A liquidus surface was determined by metallographic inspection of the as-cast alloys, combined with the differential thermal analysis data of annealed samples. The liquidus projection constructed by [2002Kre] is shown in Fig. 1. Except for the ternary invariant reactions P and E, all other



Fig. 5 Al-Mn-Si computed vertical section at 4 mass % Si [2004Du]

unmarked ternary reactions are U-type transition reactions. The phases of primary crystallization are marked in the figure. The regions of primary separation of τ_8 and τ_7 are not fully characterized. The primary separation of τ_1 and τ_3 was not observed by [2002Kre].

Isothermal Sections

Krendelsberger et al [2002Kre] annealed the as-cast alloys for 2–3 weeks at 700 $^\circ$ C or for 1 month at 550 $^\circ$ C



Fig. 6 Al-Mn-Si computed vertical section at 10 mass % Si [2004Du]

and quenched them in water. The phase equilibria were studied by x-ray powder diffraction and electron probe microanalysis. The isothermal sections constructed by [2002Kre] at 700 and 550 °C are shown in Figs. 2 and 3. The ternary phase τ_{10} is not present at these temperatures.

Computed Phase Equilibria

In their thermodynamic optimization of this system, [2004Du] employed all the experimental data of [2002Kre]. Krendelsberger et al [2002Kre] used high purity starting metals and adequate annealing times and their measured equilibria with different techniques were consistent with one another. The data of [2002Kre] were supplemented with the reviewed data of [1993Pri]. In addition, data from a vertical section at 4 mass % Si determined by [1998Rob] were used. The thermochemical data used in the optimization include the heat capacity of τ_9 from [1990Red] and the enthalpy of formation of τ_8 from [2000Leg].

The Gibbs energy of the liquid and the terminal solid solutions (fcc, bcc, A12 and A13) were modeled using a single lattice. The ternary compounds τ_1 , τ_2 , τ_3 , τ_4 , τ_5 , and τ_{10} were treated as stoichiometric compounds. A sublattice model, which is consistent with the measured structural details, was used for τ_8 and τ_9 . The ternary phase τ_6 was modeled as (Al,Mn)₄Si with a constant Si content and variation of Al and Mn within the known range. The τ_7 phase was excluded from the thermodynamic description.

Du et al[2004Du] also supplemented the experimental results of [2002Kre] by determining the liquidus temperatures of about 40 ternary alloys and used the new results in conjunction with those of [2002Kre] in the optimization. The calculated liquidus projection and the isothermal



Fig. 7 Al-Mn-Si computed vertical section at 14 mass % Si [2004Du]

sections at 700 and 550 °C were found to be in good agreement with the experimental sections shown in Figs. 1–3. The computed vertical sections at 4 mass % Mn and 4 mass % Si are shown in Figs. 4 and 5. In Figs. 6 and 7, the DTA data of [1988Zak] (not used in the optimization by [2004Du]) are compared with the vertical sections at 10 and 14 mass % Si respectively. The agreement is satisfactory.

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Section II: Phase Diagram Evaluations

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